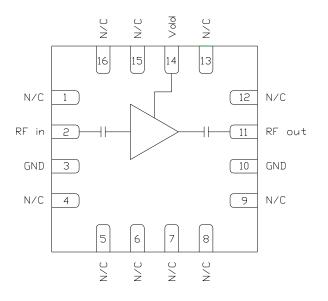
## CMD263P3

## 5-11 GHz Low Noise Amplifier

### **Product Overview**

The CMD263P3 is a broadband MMIC low noise amplifier housed in a leadless 3x3 mm plastic surface mount QFN package. The CMD263P3 is ideally suited for microwave radios and C and X-band applications where small size and low power consumption are needed. The broadband device delivers greater than 22 dB of gain with a corresponding output 1 dB compression point of +11 dBm and a noise figure of 1.4 dB. The CMD263P3 is a 50 ohm matched design eliminating the need for external DC blocks and RF port matching.

## **Functional Block Diagram**





## **Key Features**

- Ultra Low Noise Figure
- Low Current Consumption
- High Gain Broadband Performance
- Single Supply Voltage: +3.6 V @ 32 mA
- Pb-Free RoHs Compliant 3x3 QFN Package

## **Ordering Information**

Part No.	Description
CMD263P3	100 pcs on 7" reel

### **Electrical Performance** (V<sub>dd</sub> = 3.6 V, T<sub>A</sub> = 25°C, F = 8 GHz)

Parameter	Min	Тур	Max	Units
Frequency Range		5 - 11		GHz
Gain		22		dB
Noise Figure		1.4		dB
Input Return Loss		17		dB
Output Return Loss		13		dB
Output P1dB		11		dBm
Supply Current		32		mA

## **Absolute Maximum Ratings**

Parameter	Rating
Drain Voltage, V <sub>dd</sub>	5.0 V
RF Input Power	+20 dBm
Channel Temperature, Tch	150°C
Power Dissipation, Pdiss	367 mW
Thermal Resistance, Q <sub>JC</sub>	177° C/W
Operating Temperature	-40 to 85°C
Storage Temperature	-55 to 150°C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

## **Recommended Operating Conditions**

Parameter	Min	Тур	Max	Units
V <sub>dd</sub>	2.0	3.6	4.5	V
l <sub>dd</sub>		32		mA

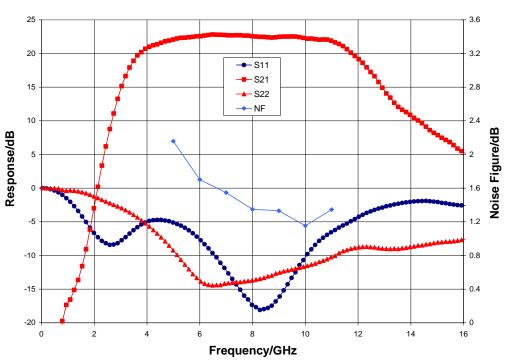
Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

## **Electrical Specifications** (V<sub>dd</sub> = 3.6 V, T<sub>A</sub> = 25°C)

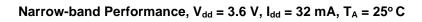
Parameter	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range		5 - 8.5			8.5 - 11		GHz
Gain	19	22	26	19	22	26	dB
Noise Figure		1.6	2.4		1.3	1.7	dB
Input Return Loss		10			10		dB
Output Return Loss		13			12		dB
Output P1dB		11			11.5		dBm
Output IP3		21			21		dBm
Supply Current	22	32	42	22	32	42	mA
Gain Temperature Coefficient		0.013			0.013		dB/°C
Noise Figure Temperature Coefficient		0.008			0.008		dB/°C

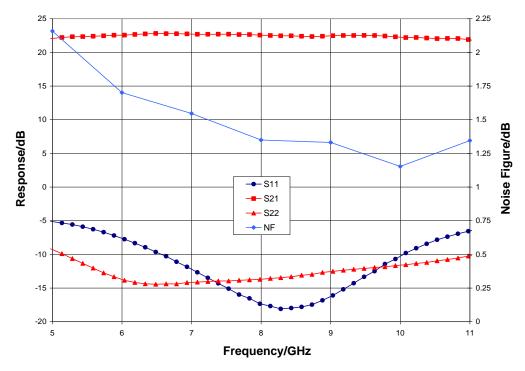


## **Typical Performance**



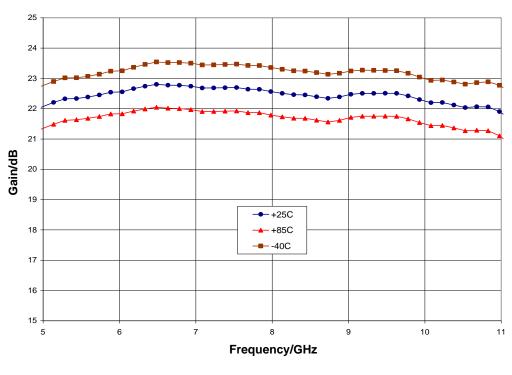
Broadband Performance,  $V_{dd}$  = 3.6 V,  $I_{dd}$  = 32 mA,  $T_A$  = 25° C



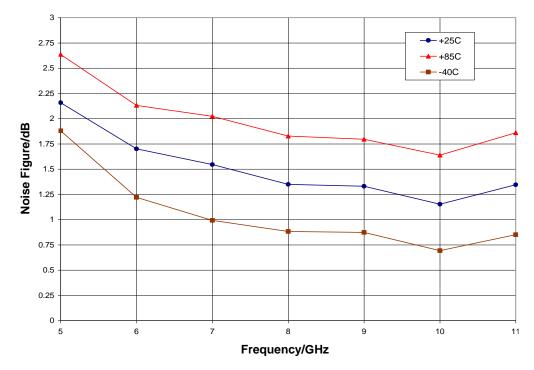




## **Typical Performance**





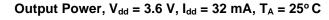


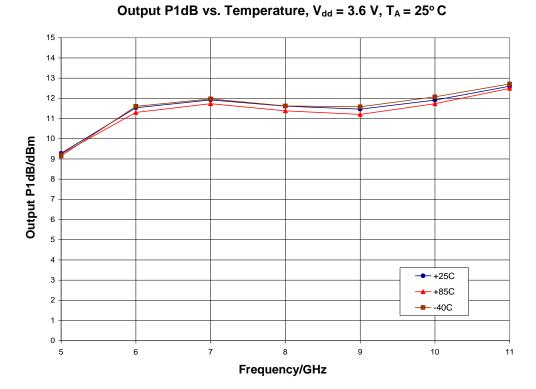
Gain vs. Temperature,  $V_{dd}$  = 3.6 V



## **Typical Performance**

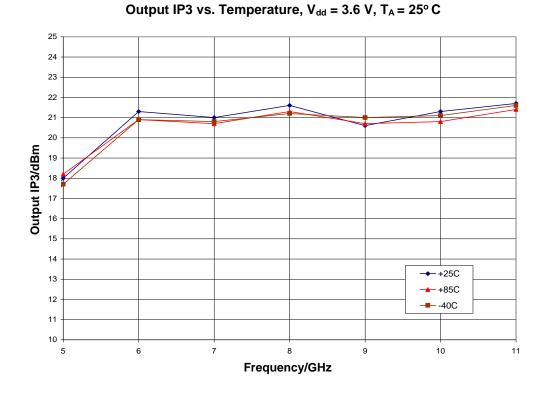
- P1dB - Psat Response/dBm Frequency/GHz







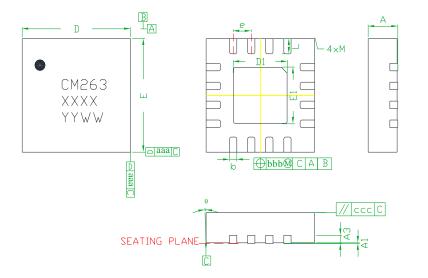
## **Typical Performance**



## CMD263P3 5-11 GHz Low Noise Amplifier

## **Mechanical Information**

#### **Package Information and Dimensions**



	1					
SYMBOLS	DIMENSIONS IN MILLIMETERS					
	MIN	NOM	MAX			
А	0.80	0.90	1.00			
A1	0	0.02	0.05			
A3		0.25REF.				
b	0.18	0.23	0.30			
D	2.85	3.00	3.15			
D1		1.5BSC				
Е	2.85	3.00	3.15			
E1		1.5BSC				
e		0.50BSC				
L	0.30	0.40	0.50			
θ	0		12			
aaa		0.25				
bbb		0.10				
ccc		0.10				
М			0.05			

#### Notes:

- 1. Dimensions are in millimeters
- 2. RoHS compliant mold compound
- 3. Lead frame material: Copper alloy
- 4. Lead finish: Electroless nickel electroless palladium
- 5. Immersion gold (ENEPIG) plating in accordance with IPC 4556
- 6. Indicated dimension/tolerance applies to leads and exposed pads

#### **Recommended PCB Land Pattern**

Qorvo recommends that the user develop the land pattern that will provide the best design for proper solder reflow and device attach for their specific application. Please review Qorvo Application Note AN 105 for a recommended land pattern approach.

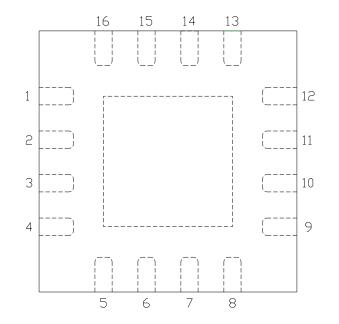
#### **Recommended Solder Reflow Profile**

Qorvo recommends screen printing with belt furnace reflow to ensure proper solder reflow and device attach. Please review Qorvo Application Note AN 102 for a recommended solder reflow profile.

## CMD263P3 5-11 GHz Low Noise Amplifier

## **Pin Description**

#### Pin Diagram



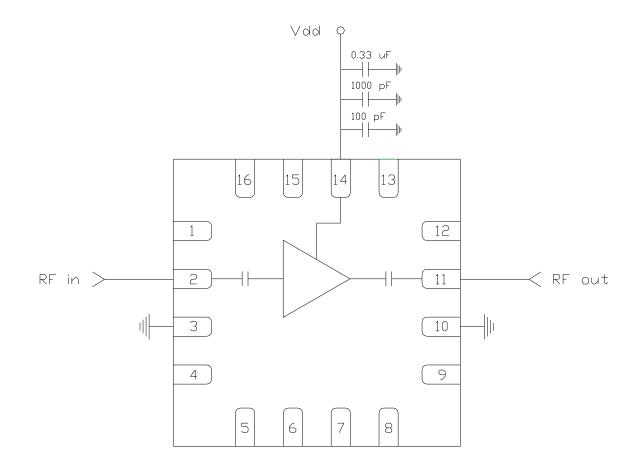
#### **Functional Description**

Pin	Function	Description	Schematic
1, 4 - 9, 12, 13, 15, 16	N/C	No connection required These pins may be connected to RF / DC ground	
2	RF in	DC blocked and 50 ohm matched	RF in O
3, 10, and die paddle	Ground	Connect to RF / DC ground	GND =
11	RF out	DC blocked and 50 ohm matched	RF out
14	V <sub>dd</sub>	Power supply voltage Decoupling and bypass caps required	Vdd =



## **Applications Information**

#### **Application Circuit**



#### **Biasing and Operation**

The CMD263P3 is biased with a single positive drain supply. Performance is optimized when the drain voltage is set to +3.6 V, though it may be set to a minimum of +2.0 V and a maximum of +4.5 V.

RF power can be applied at any time.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

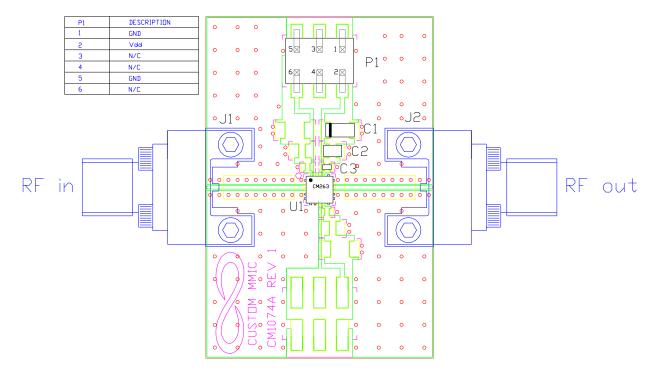


## **Applications Information**

#### **Evaluation Board**

The circuit board shown has been developed for optimized assembly at Qorvo. A sufficient number of via holes should be used to connect the top and bottom ground planes. As surface mount processes vary, careful process development is recommended.





## **Bill of Material**

Designator	Value	Description		
J1, J2		SMA End Launch Connector		
P1		6 Pin Header		
C1	0.33 µF	Capacitor, Tantalum		
C2	1000 pF	Capacitor, 0603		
C3	100 pF	Capacitor, 0402		
U1		CMD263P3 Low Noise Amplifier		
PCB		CM1074A Evaluation PCB		

## **CMD263P3** 5-11 GHz Low Noise Amplifier

## **Handling Precautions**

Parameter	Rating	Standard		On the l
ESD – Human Body Model (HBM)	Class 1A	ESDA/JEDEC JS-001-2012		Caution! ESD-Sensitive Device
MSL-Moisture Sensitivity Level	Level 1	IPC/JEDEC J-STD-020	J.C.	ESD-Sensitive Device

## **RoHS Compliance**

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C15H12Br402) Free
- SVHC Free
- PFOS Free
- Halogen Free

## **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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